TOSHIBA Photocoupler IRED & Photo-IC

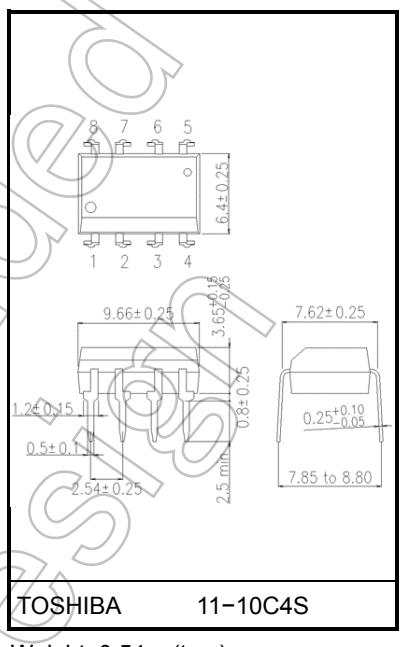
TLP2200

Isolated Bus Driver
High Speed Line Receiver
Microprocessor System Interfaces
MOS FET Gate Driver
Direct Replacement for HCPL−2200

The TOSHIBA TLP2200 consists of an infrared emitting diode and integrated high gain, high speed photodetector.
This unit is 8−lead DIP package.
The detector has a three state output stage that eliminates the need for pull−up resistor, and built−in Schmitt trigger. The detector IC has an internal shield that provides a guaranteed common mode transient immunity of 1000V / μs.

- Input current: I_F = 1.6 mA
- Power supply voltage: V_{CC} = 4.5 to 20 V
- Switching speed: 2.5MBd guaranteed
- Common mode transient immunity: ±1000V / μs (min)
- Guaranteed performance over temperature: 0 to 85°C
- Isolation voltage: 2500 Vrms (min)
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A
  File No.E67349

Unit: mm



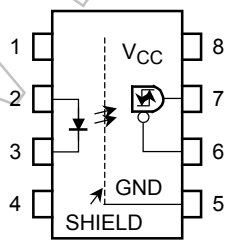
TOSHIBA 11−10C4S

Weight: 0.54 g (typ.)

Truth Table (positive logic)

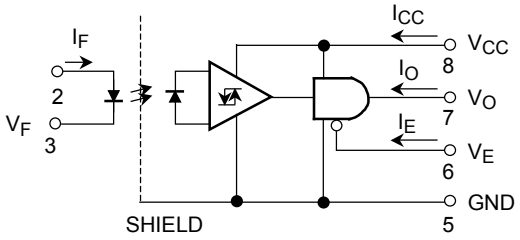
Input	Enable	Output
H	H	Z
L	H	Z
H	L	H
L	L	L

Pin Configuration (top view)



1: N.C.
2: Anode
3: Cathode
4: N.C.
5: GND
6: V_E (enable)
7: V_O (output)
8: V_{CC}

Schematic



Start of commercial production
1986-07

Recommended Operating Conditions

Characteristic	Symbol	Min	Typ.	Max	Unit
Input current, on	$I_{F(ON)}$	1.6	—	5	mA
Input current, off	$I_{F(OFF)}$	0	—	0.1	mA
Supply voltage	V_{CC}	4.5	—	20	V
Enable voltage high	V_{EH}	2.0	—	20	V
Enable voltage low	V_{EL}	0	—	0.8	V
Fan out (TTL load)	N	—	—	4	—
Operating temperature	T_{opr}	0	—	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Absolute Maximum Ratings (no derating required up to 70°C)

Characteristic			Symbol	Rating	Unit
LED	Forward current		I_F	10	mA
	Peak transient forward current	(Note 1)	I_{FPT}	1	A
	Reverse voltage		V_R	5	V
	Input Power Dissipation		P_D	45	mW
	Input power dissipation derating (Ta ≥ 70°C)		$\Delta P_D/\Delta Ta$	-0.86	mW/°C
Detector	Output current		I_O	25	mA
	Supply voltage		V_{CC}	−0.5 to 20	V
	Output voltage		V_O	−0.5 to 20	V
	Three state enable voltage		V_E	−0.5 to 20	V
	Output Power Dissipation		P_O	100	mW
	Output Power Dissipation Derating (Ta ≥ 70°C)		ΔP_O /°C	-1.9	mW/°C
	Total package power dissipation	(Note 2)	P_T	210	mW
Operating temperature range			T_{opr}	−40 to 85	°C
Storage temperature range			T_{stg}	−55 to 125	°C
Lead solder temperature (10 s) (**)			T_{sol}	260	°C
Isolation voltage (AC 60 s, R.H. ≤ 60 %,Ta = 25°C)		(Note 3)	BV_S	2500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) Pulse width 1 μs, 300 pps.

(Note 2) Derate 4.5 mW / °C above 70 °C ambient temperature.

(Note 3) Device considered a two terminal device: Pins 1, 2, 3 and 4 shorted together, and pins 5,6,7 and 8 shorted together

(**) 1.6 mm below seating plane.

Electrical Characteristics (unless otherwise specified, Ta = 0 to 85 °C, V_{CC} = 4.5 to 20 V, $I_{F(ON)}$ = 1.6 to 5 mA, $I_{F(OFF)}$ = 0 to 0.1 mA, V_{EL} = 0 to 0.8 V, V_{EH} = 2.0 to 20 V)

Characteristic	Symbol	Test Condition		Min	Typ.*	Max	Unit
Output leakage current (V_O > V_{CC})	I_{OHH}	I_F = 5 mA, V_{CC} = 4.5 V	V_O = 5.5 V	—	—	100	μA
			V_O = 20 V	—	2	500	
Logic low output voltage	V_{OL}	I_{OL} = 6.4 mA (4 TTL load)		—	0.32	0.5	V
Logic high output voltage	V_{OH}	I_{OH} = −2.6 mA		2.4	3.4	—	V
Logic low enable current	I_{EL}	V_E = 0.4 V		—	−0.13	−0.32	mA
Logic high enable current	I_{EH}	V_E = 2.7 V		—	—	20	μA
		V_E = 5.5 V		—	—	100	
		V_E = 20 V		—	0.01	250	
Logic low enable voltage	V_{EL}	—		—	—	0.8	V
Logic high enable voltage	V_{EH}	—		2.0	—	—	V
Logic low supply current	I_{CCL}	I_F = 0 mA, V_E = don't care	V_{CC} = 5.5 V	—	5	6.0	mA
			V_{CC} = 20 V	—	5.6	7.5	
Logic high supply current	I_{CCH}	I_F = 5 mA, V_E = don't care	V_{CC} = 5.5 V	—	2.5	4.5	mA
			V_{CC} = 20 V	—	2.8	6.0	
High impedance state output current	I_{OZL}	I_F = 5 mA, V_E = 2 V	V_O = 0.4 V	—	1	−20	μA
	I_{OZH}	I_F = 0 mA, V_E = 2 V	V_O = 2.4 V	—	—	20	
			V_O = 5.5 V	—	—	100	
			V_O = 20 V	—	0.01	500	
Logic low short circuit output current (Note 4)	I_{OSL}	I_F = 0 mA	V_O = V_{CC} = 5.5 V	25	55	—	mA
			V_O = V_{CC} = 20 V	40	80	—	
Logic high short circuit output current (Note 4)	I_{OSH}	I_F = 5 mA, V_O = GND	V_{CC} = 5.5 V	−10	−25	—	mA
			V_{CC} = 20 V	−25	−60	—	
Input current hysteresis	I_{HYS}	V_{CC} = 5 V		—	0.05	—	mA
Input forward voltage	V_F	I_F = 5 mA, Ta = 25 °C		—	1.55	1.7	V
Temperature coefficient of forward voltage	ΔV_F / ΔTa	I_F = 5 mA		—	−2.0	—	mV / °C
Input reverse breakdown voltage	BV_R	I_R = 10 μA, Ta = 25 °C		5	—	—	V
Input capacitance	C_{IN}	V_F = 0 V, f = 1 MHz, Ta = 25 °C		—	45	—	pF
Resistance (input−output)	R_{I-O}	V_{I-O} = 500 V R.H. ≤ 60 % (Note 3)		5×10^{10}	10^{14}	—	Ω
Capacitance (input−output)	C_{I-O}	V_{I-O} = 0 V, f = 1 MHz (Note 3)		—	0.6	—	pF

(**) All typ. values are at Ta = 25 °C, V_{CC} = 5 V, $I_{F(ON)}$ = 3 mA unless otherwise specified.

Switching Characteristics

(unless otherwise specified, Ta = 0 to 85 °C, V_{CC} = 4.5 to 20 V, $I_{F(ON)}$ = 1.6 to 5 mA, $I_{F(OFF)}$ = 0 to 0.1 mA)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Propagation delay time to logic high output level (Note 5)	t_{pLH}	1	Without peaking capacitor C_1	—	235	—	ns
			With peaking capacitor C_1	—	—	400	
Propagation delay time to logic low output level (Note 5)	t_{pHL}		Without peaking capacitor C_1	—	250	—	ns
			With peaking capacitor C_1	—	—	400	
Output rise time (10−90%)	t_r		—	—	35	—	ns
Output fall time (90−10%)	t_f			—	20	—	ns
Common mode transient immunity at logic high output (Note 6)	CM_H	3	I_F = 1.6 mA, V_{CM} = 50 V, Ta = 25 °C	−1000	—	—	V / μs
Common mode transient immunity at logic low output (Note 6)	CM_L		I_F = 0 mA, V_{CM} = 50 V, Ta = 25 °C	1000	—	—	V / μs

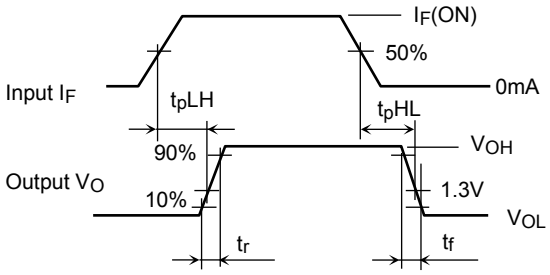
(*) All typ. values are at Ta = 25 °C, V_{CC} = 5 V, $I_{F(ON)}$ = 3 mA unless otherwise specified.

(Note 4) Duration of output short circuit time should not exceed 10ms.

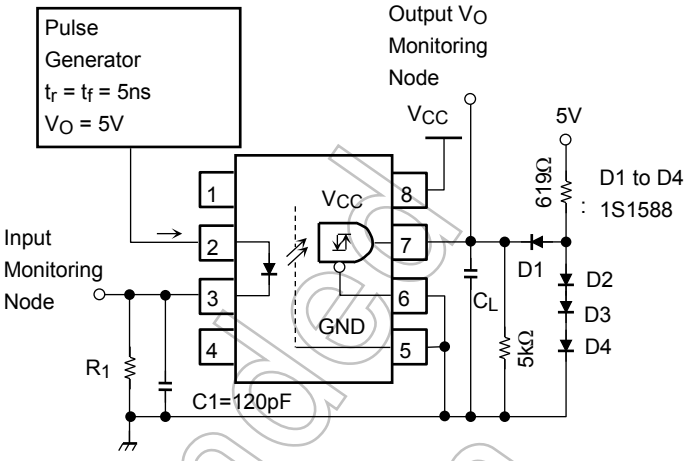
(Note 5) The t_{pLH} propagation delay is measured from the 50 % point on the leading edge of the input pulse to the 1.3 V point on the leading edge of the output pulse.
The t_{pHL} propagation delay is measured from the 50 % point on the trailing edge of the input pulse to the 1.3 V point on the trailing edge of the output pulse.

(Note 6) CM_L is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic low state (V_O < 0.8 V).
CM_H is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic high state (V_O > 2.0 V).

Test Circuit 1 t_{pHL}, t_{pLH}, t_r and t_f

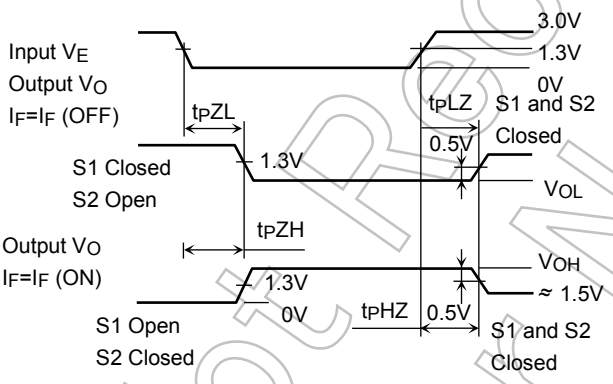


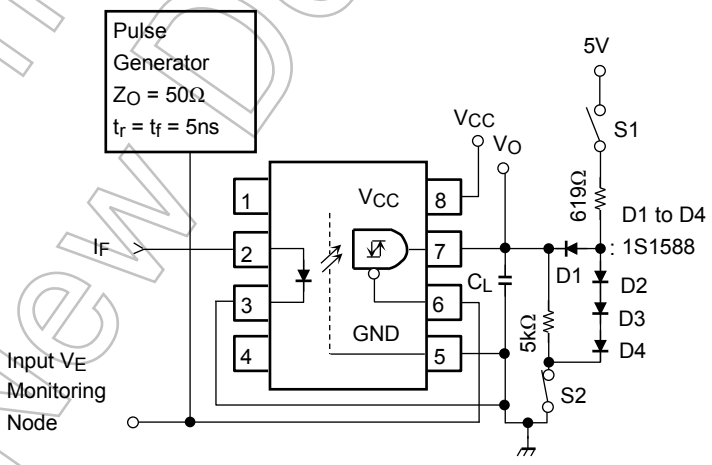
R_1	2.15kΩ	1.1kΩ	681Ω
$I_{F(ON)}$	1.6mA	3mA	5mA



C_1 is peaking capacitor. The probe and jig capacitances are included in C_1.
C_L is approximately 15pF which includes probe and stray wiring capacitance.

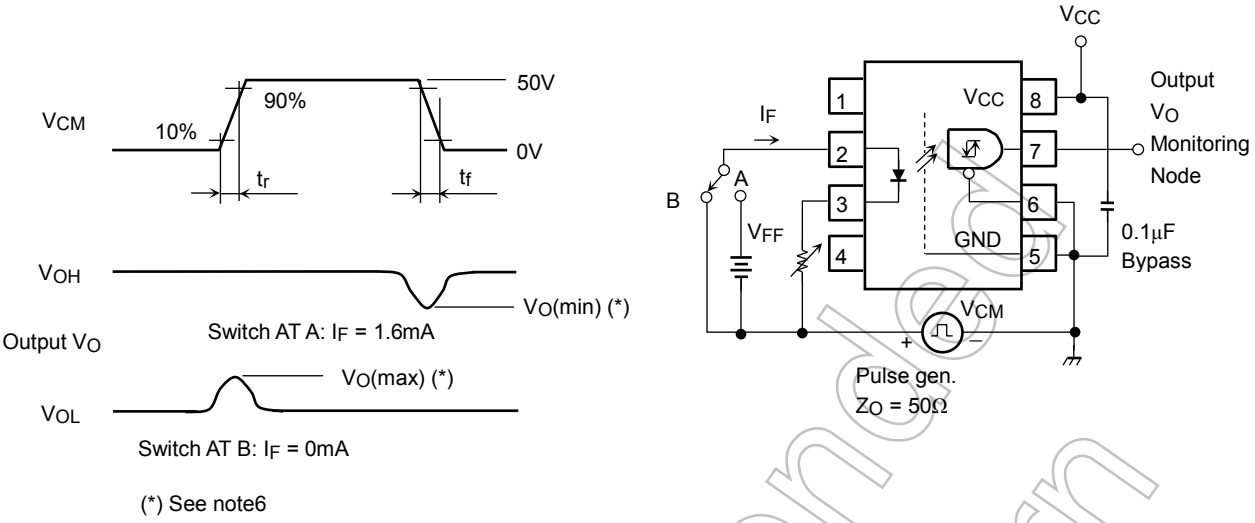
Test Circuit 2 t_{pHZ}, t_{pZH}, t_{pLZ} and t_{pZL}





C_L is approximately 15pF which includes probe and stray wiring capacitance.

Test Circuit 3 Common Mode Transient Immunity



(*) See note6

RESTRICTIONS ON PRODUCT USE

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as “TOSHIBA”.
Hardware, software and systems described in this document are collectively referred to as “Product”.

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. **TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.**
- **PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE").** Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant. **IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT.** For details, please contact your TOSHIBA sales representative or contact us via our website.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- **ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.**
- GaAs (Gallium Arsenide) is used in Product. GaAs is harmful to humans if consumed or absorbed, whether in the form of dust or vapor. Handle with care and do not break, cut, crush, grind, dissolve chemically or otherwise expose GaAs in Product.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. **TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.**

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for High Speed Optocouplers ***category:***

Click to view products by Toshiba ***manufacturer:***

Other Similar products are found below :

HCPL-2201-300 TLP558(F) JAN4N24 610737H HCPL2630M HCPL2731SM HCPL2630SM PS9817A-1-F3-AX TLP2766A(E EL816S2(C)(TU)-F TLP281-4 TLP290(V4GBTP,SE(T PS9121-F3-AX PS9123-F3-AX HCPL2531S HCPL2631SD HCPL-4661-500E TLP118(TPL,E) TLP521-2XGB TLP621-2XGB 4N46-300E JANTXV4N24U SFH6318T 6N135-300E TIL198 TLP2309(TPL,E) TLP2355(TPL,E TLP521-4GR TLP521-4XGB TLP621-4X TLP621XSM IS281-4GB IS181GR ICPL2631 ICPL2630 ICPL2531 ICPL2601 TLP2301(E(T TLP714(F) TLP754(F) FOD260LSDV ACPL-M21L-500E ACPL-064L-500E PS2501-1XSM PS2505-1 PS2561L2-1-F3-A PS2913-1-F3-AX PS9821-2-F3-AX FOD0721R2 FODM8061R2V